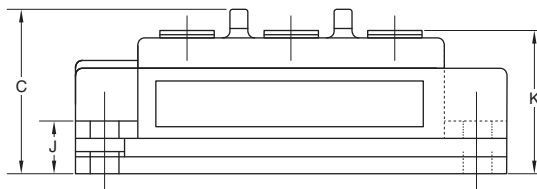
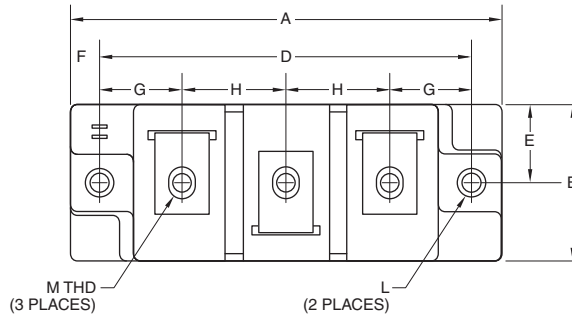


Fast Recovery Diode Module 100 Amperes/3300 Volts



Description:

High voltage diodes feature highly insulating housings that offer enhanced protection by means of greater creepage and strike clearance distance for many demanding applications like medium voltage drives and auxiliary traction applications.

Features:

- ☐ Alumina Ceramic Substrate for Low Thermal Impedance
- ☐ Copper Baseplate
- ☐ Fast Recovery Time (1.2 μ s max.)
- ☐ Industry Standard Packages Allow Common Bus Work to Complementary High Isolation Diodes
- ☐ No Additional Insulation Components Required

Applications:

- ☐ High Voltage Power Supplies
- ☐ Medium Voltage Drives
- ☐ Motor Drives
- ☐ Traction

Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	3.70	94.0
B	1.34	34.0
C	1.40	35.6
D	3.15	80.0
E	0.67	17.0
F	0.28	6.99

Dimensions	Inches	Millimeters
G	0.67	17.1
H	0.91	23.0
J	0.36	9.0
K	1.18	30.0
L	0.216 Dia.	5.5 Dia.
M	#10-32	#10-32

QR_3310002**Fast Recovery Diode Module**

100 Amperes/3300 Volts

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	QRD3310002 QRC3310002	Units
Repetitive Peak Reverse Blocking Voltage	V_{RRM}	3300	Volts
Non-Repetitive Peak Reverse Blocking Voltage	V_{RSM}	$V_{RRM} + 100$	Volts
Average Forward Current	$T_C = 80^\circ\text{C}$	$I_F(\text{avg})$	60 Amperes
	$T_C = 25^\circ\text{C}$	$I_F(\text{avg})$	90 Amperes
Forward Current (Pulse)	I_{FM}	200	Amperes
Operating Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 150	$^\circ\text{C}$
Maximum Mounting Torque, #10-32 Mounting Screw	—	26	in-lb
Maximum Terminal Torque, #10-32 Terminal Screw	—	26	in-lb
Module Weight (Typical)	—	250	Grams
V Isolation (60 Hz, Circuit to Base, All Terminals Shorted, $t = 1$ sec.)	V_{RMS}	6000	Volts

IGBT Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Peak Reverse Leakage Current	I_{RRM}	Rated V_{RRM}	—	—	5	mA
Peak On-State Voltage	V_{FM}	$I_F = 100\text{A}$	—	3.3	4.3	Volts
Reverse Recovery Time	t_{rr}	$I_F = 100\text{A}$, $di/dt = -200\text{A}/\mu\text{s}$	—	—	1.2	μs
Reverse Recovery Charge	Q_{rr}	$I_F = 100\text{A}$, $di/dt = -200\text{A}/\mu\text{s}$	—	25	—	μC

Thermal and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

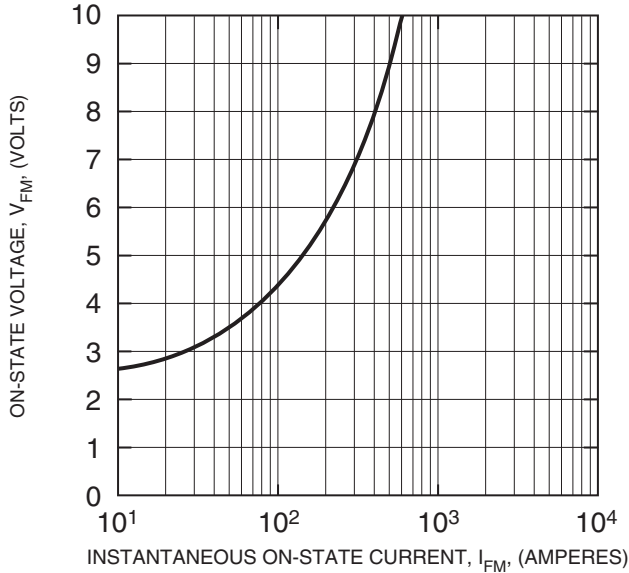
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{th(j-c)Q}$	Per Diode	—	—	0.20	$^\circ\text{C}/\text{W}$
Thermal Resistance, Case to Sink Lubricated	$R_{th(c-s)Q}$	Per Module	—	—	0.05	$^\circ\text{C}/\text{W}$

QR_3310002

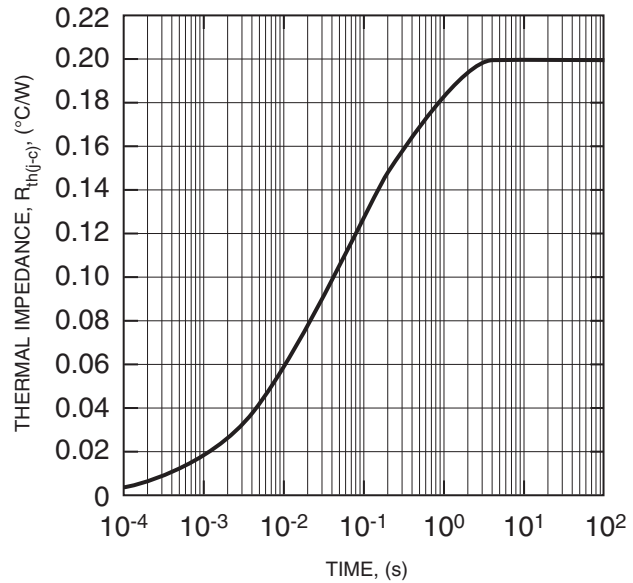
Fast Recovery Diode Module

100 Amperes/3300 Volts

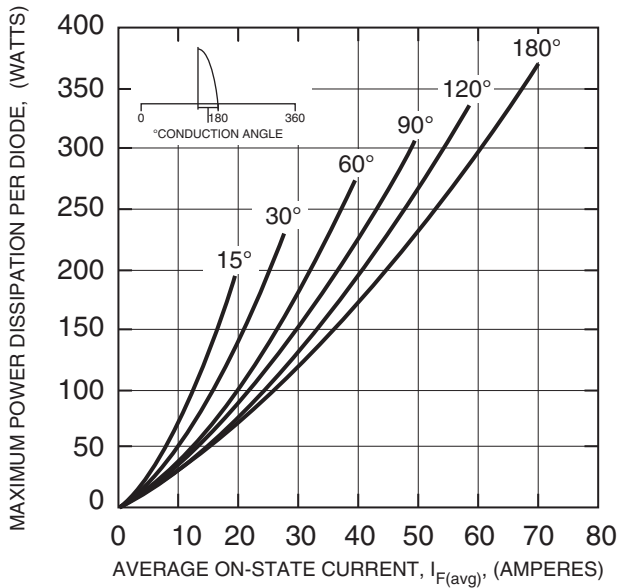
**MAXIMUM ON-STATE FORWARD
VOLTAGE DROP CHARACTERISTICS
($T_J = 150^\circ\text{C}$)**



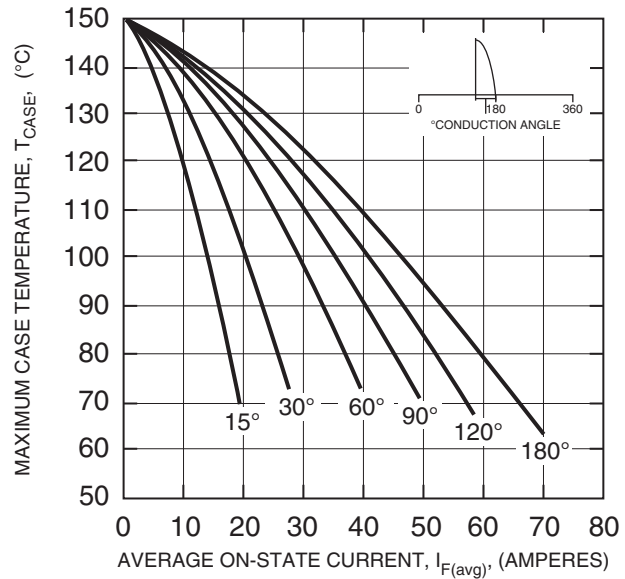
**MAXIMUM TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(JUNCTION TO CASE)**



**MAXIMUM ON-STATE
POWER DISSIPATION
(SINUSOIDAL WAVEFORM)**



**MAXIMUM ALLOWABLE
CASE TEMPERATURE
(SINUSOIDAL WAVEFORM)**



QR_3310002

Fast Recovery Diode Module

100 Amperes/3300 Volts

